CSD-4M CSD-4N

SURFACE MOUNT SILICON CONTROLLED RECTIFIERS 4.0 AMP, 600 THRU 800 VOLT



www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CSD-4M and CSD-4N are epoxy molded SCRs designed for sensing circuit and control system applications.



MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T _C =25°C unless otherw	IUM RATINGS: (T _C =25°C unless otherwise noted)						
	SYMBOL	CSD-4M	CSD-4N	UNITS			
Peak Repetitive Off-State Voltage	V _{DRM} , V _{RRM}	600	800	V			
RMS On-State Current (T _C =85°C)	IT(RMS)	4.	0	А			
Peak One Cycle Surge Current, t=10ms	ITSM	3	0	А			
I ² t Value for Fusing, t=10ms	l ² t	4.	5	A ² s			
Peak Gate Power, tp=20µs	PGM	3.	0	W			
Average Gate Power Dissipation	P _G (AV)	0.	2	W			
Peak Gate Current, tp=20µs	IGM	1.	2	А			
Critical Rate of Rise of On-State Current	di/dt	5	0	A/µs			
Operating Junction Temperature	Тј	-40 to	+125	°C			
Storage Temperature	T _{stg}	-40 to	+150	°C			

ELECTRICAL CHARACTERISTICS: (T_C=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I _{DRM} , I _{RRM}	Rated V _{DRM} , V _{RRM} , R _{GK} =1KΩ			10	μA
IDRM, IRRM	Rated V _{DRM} , V _{RRM} , R _{GK} =1KΩ, T _C =125°C			200	μA
lgt	V _D =12V, R _L =10Ω	20	38	200	μA
Ι _Η	I _T =50mA, R _{GK} =1KΩ		0.25	2.0	mA
V _{GT}	V _D =12V, R _L =10Ω		0.55	0.8	V
V_{TM}	I _{TM} =8.0A, tp=380µs		1.6	1.8	V
dv/dt	V _D = ² / ₃ V _{DRM} , R _{GK} =1KΩ, T _C =125°C	10			V/µs





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$\begin{array}{c|c} & H \\ \hline \\ & J \\ \hline \\ & 4 \\ \hline \\ & 4 \\ \hline \\ & 1 \\ & 2 \\ \hline \\ & 1 \\ & 2 \\ \hline \\ & 1 \\ & 2 \\ \hline \\ & R \\ \hline \\ & R \\ \hline \\ & P \\ \hline \\ & R \\ \hline \\ & R \\ & R \\ \hline \\ & R \\ & R$

LEAD CODE:

- 1) Cathode
- 2) Anode
- 3) Gate
- 4) Anode

MARKING: FULL PART NUMBER

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
A	0.083	0.108	2.10	2.75			
В	0.016	0.035	0.40	0.89			
С	0.035	0.063	0.89	1.60			
D	0.203	0.228	5.15	5.79			
E	0.020	-	0.51	-			
F	0.016	0.024	0.40	0.60			
G	0.061		1.55				
Н	0.248	0.268	6.30	6.81			
J	0.195	0.217	4.95	5.50			
K	0.209	0.245	5.30	6.22			
L	0.033		0.83				
М	0.090	0.115	2.30	2.91			
N	0.012	0.045	0.30	1.14			
Р	0.180		4.60				
R	0.090		2.30				

DPAK(REV:R2)

DPAK CASE - MECHANICAL OUTLINE

OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- · Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities

ss your design challenges.

· Custom product packing

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits

Custom bar coding for shipments

Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

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